



# MG150HF12LEC2

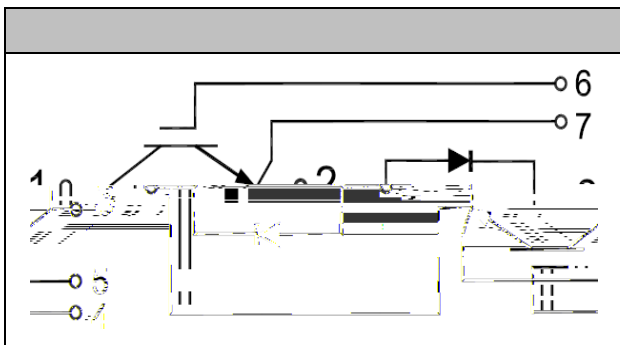


## IGBT Modules

$V_{CES}$	1200V
$I_c$	150A

## Applications

- High frequency drivers
- Solar inverters
- UPS (Uninterruptible Power Supplies)
- Electric welding machine



## Features

- High speed IGBT in NPT technology
- Low switching losses
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance
- Maximum junction temperature 150

## ● IGBT

### Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Collector-Emitter Voltage	$V_{CES}$	$V_{GE}=0V, I_c = 1mA, T_{vj}=25$	1200	V
Continuous Collector Current	$I_c$	$T_c=80$	150	A
Repetitive Peak Collector Current	$I_{CRM}$	$t_p=1ms$	300	A
Gate-Emitter Voltage	$V_{GES}$	$T_{vj}=25$	20	V
Total Power Dissipation	$P_{tot}$	$T_c=25$ $T_{vjmax}=150$	1136	W



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## Characteristic values

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Parameter	Symbol	Conditions	Value	Unit
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## ● Diode

### Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	$T_{vj}=25$	1200	V
Continuous DC Forward Current	$I_F$		150	A
Repetitive Peak Forward Current	$I_{FRM}$	$t_p=1\text{ms}$	300	A

### Characteristic values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F=150\text{A}, T_{vj}=25$		1.90	2.40	V
		$I_F=150\text{A}, T_{vj}=125$		1.95		
Recovered Charge	$Q_{rr}$	$I_F=150\text{A}$		6.8		$\mu\text{C}$
Peak Reverse Recovery Current	$I_{rr}$	$V_R=600\text{V}$ $-di_F/dt=1400\text{A}/\mu\text{s}$		145		A
Reverse Recovery Energy	$E_{rec}$	$T_{vj}=25$		4.1		mJ
Recovered Charge	$Q_{rr}$	$I_F=150\text{A}$		14.5		$\mu\text{C}$
Peak Reverse Recovery Current	$I_{rr}$	$V_R=600\text{V}$ $-di_F/dt=1400\text{A}/\mu\text{s}$		160		A
Reverse Recovery Energy	$E_{rec}$	$T_{vj}=125$		8.4		mJ



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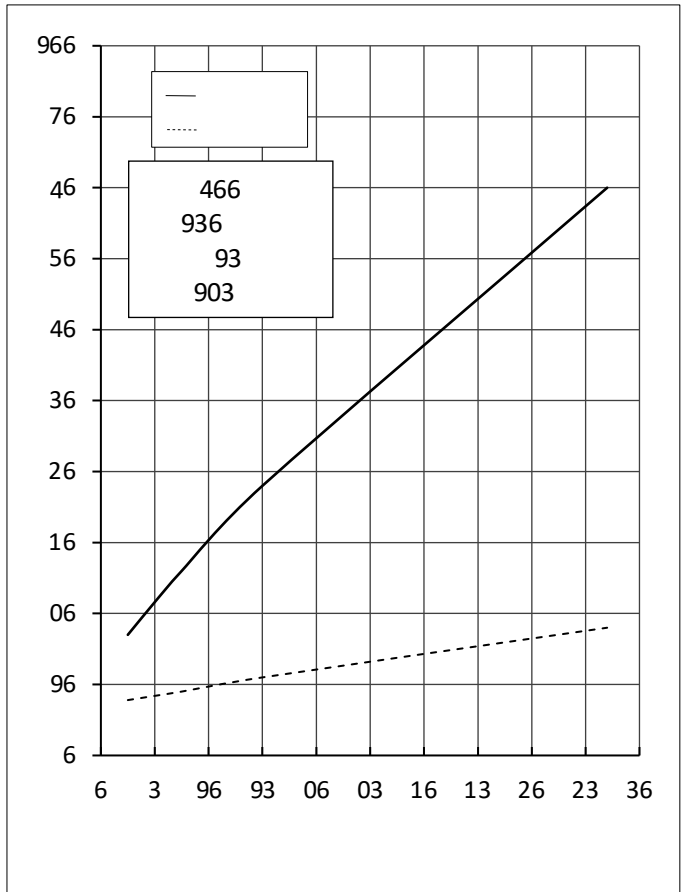
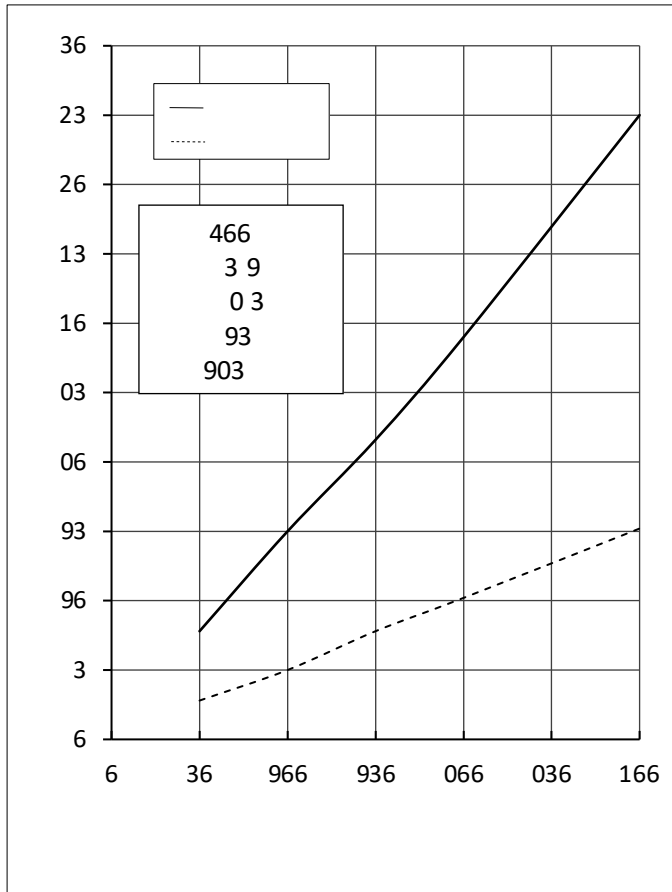
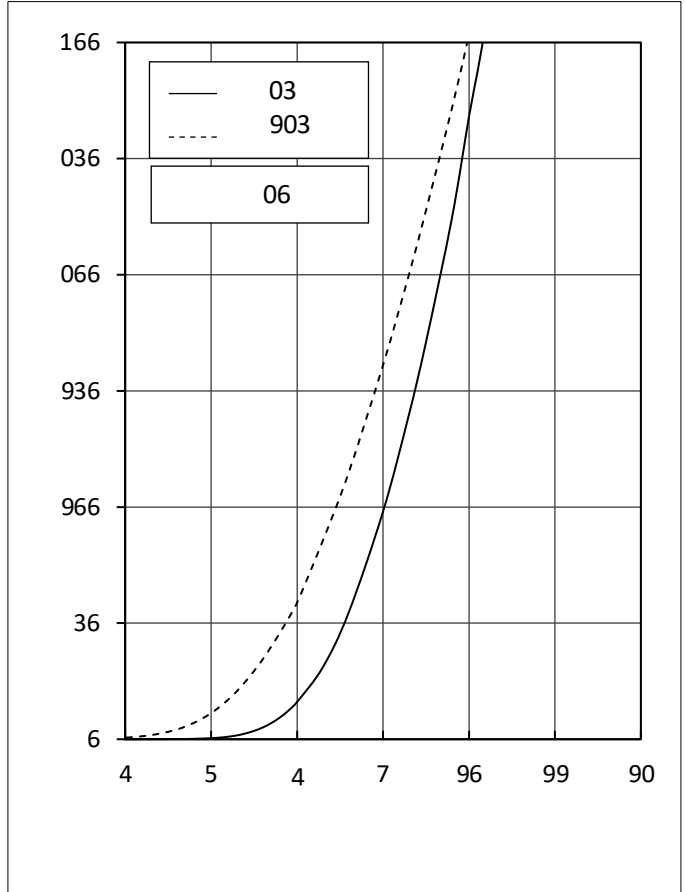
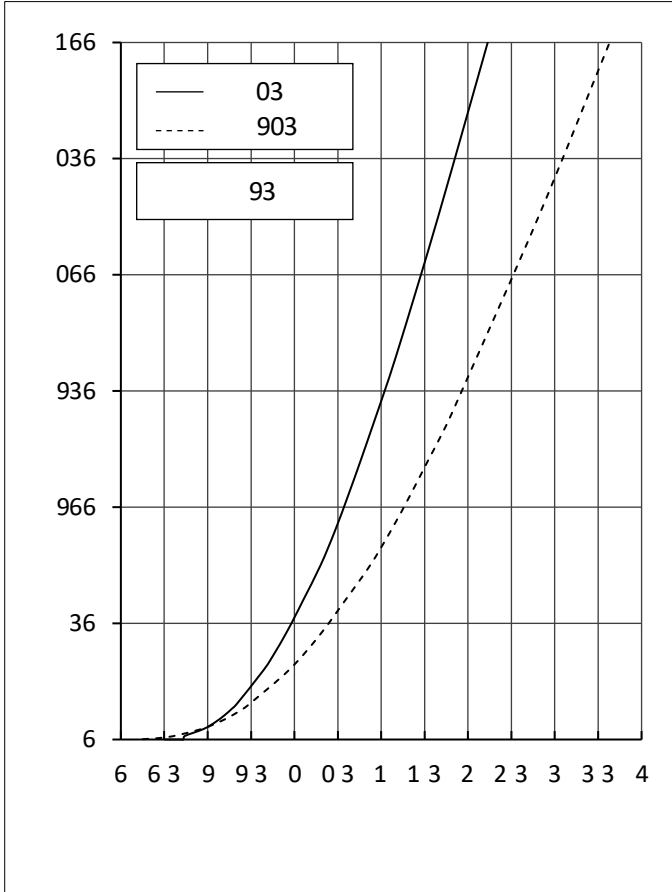


● **Module Characteristics**  $T_C=25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Isolation voltage	$V_{\text{isol}}$	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature	$T_{\text{jmax}}$				150	



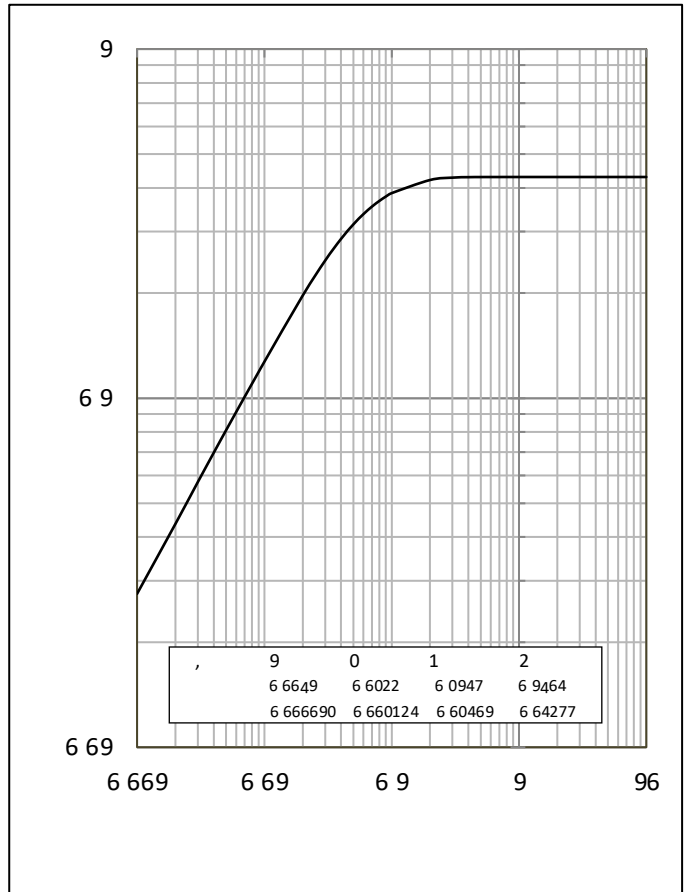
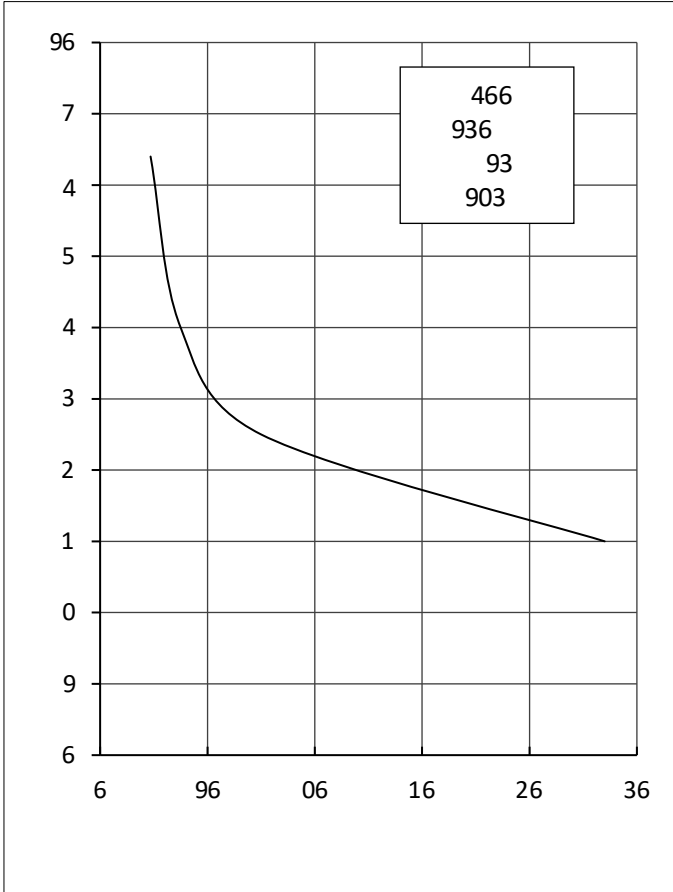
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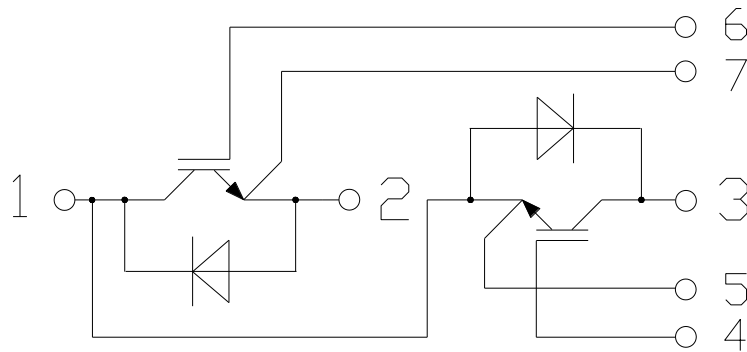
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## ● Circuit Diagram



## ● Package Outline Information

Dimensions in Millimeters

